









SN55173, SN75173 SLLS144F - OCTOBER 1980 - REVISED OCTOBER 2023

# **SNx5173 Quadruple Differential Line Receivers**

#### 1 Features

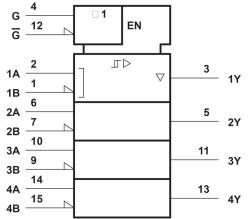
- Meet or exceed the requirements of TIA/EIA-422-B, TIA/EIA-423-B, and TIA/EIA-485-A and ITU recommendations V.10, V.11, X.26, and X.27
- Designed for multipoint bus transmission on long bus lines in noisy environments
- 3-State outputs
- Common-mode input voltage range of -12 V to 12 V
- Input sensitivity: ±200 mV
- Input hysteresis: 50 mV typical
- High Input Impedance :  $12 \text{ k}\Omega$  minimum
- Operate from single 5-V supply
- Low power requirements
- Pin-to-pin replacement for AM26LS32

## 2 Applications

- Motor drives
- Factory automation and control

## 3 Description

The SN55173 and SN75173 are monolithic quadruple differential line receivers with 3-state outputs. They are designed to meet the requirements of TIA/EIA-422-B, TIA/EIA-423-B, TIA/EIA-485-A, and several ITU recommendations. The standards are for balanced multipoint bus transmission at rates up to



- A. This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, and N packages.
- Pin numbers shown are for the D, J, and N packages.

#### Logic Symbol

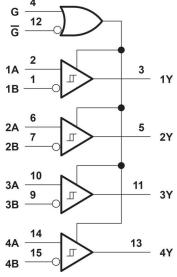
10 megabits per second. The four receivers share two OR enable inputs, one active when high, the other active when low. These devices feature high input impedance, input hysteresis for increased noise immunity, and input sensitivity of ± 200 mV over a common-mode input voltage range of - 12 V to 12 V. Fail-safe design specifies that if the inputs are open circuited, the outputs are always high. The SN65173 and SN75173 are designed for optimum performance when used with the SN75172 or SN75174 quad differential line drivers.

The SN55173 is characterized over the full military temperature range of – 55°C to 125°C. The SN75173 is characterized for operation from 0°C to 70°C.

#### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)		
SN55173	J (CDIP, 16)	6.92 mm × 19.56 mm		
SN33173	FK (LCCC, 20) <sup>(3)</sup>	8.89 mm × 8.89 mm		
	D (SOIC, 16)	9.9 mm × 6 mm		
SN75173	N (PDIP, 16)	19.3 × 9.4 mm		
	NS (SO, 16)	10.2 × 7.8 mm		

- (1) For more information, see Section 11.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- Not recommended for new designs.



Logic Diagram (Positive Logic)



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	1355566	1 7.1 Device Functional Modes



# **4 Pin Configuration and Functions**

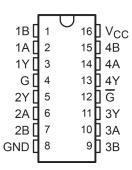
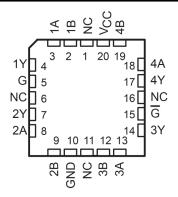


Figure 4-1. SN55173: J Package SN75173: D, N or NS Package (Top View)

**Table 4-1. Pin Functions** 

PIN TYPE#no		TYPE#non	DESCRIPTION
NAME	NO.	e#	DESCRIPTION
1B	1	ı	Channel 1 Differential Receiver Inverting Input
1A	2	I	Channel 1 Differential Receiver Non-Inverting Input
1Y	3	0	Channel 1 Single Ended Output
G	4	I	Active High Enable
2Y	5	0	Channel 2 Single Ended Output
2A	6	I	Channel 2 Differential Receiver Non-Inverting Input
2B	7	I	Channel 2 Differential Receiver Inverting Input
GND	8	GND	Device GND
3B	9	I	Channel 3 Differential Receiver Inverting Input
3A	10	I	Channel 3 Differential Receiver Non-Inverting Input
3Y	11	0	Channel 3 Single Ended Output
G	12	I	Active Low Enable
4Y	13	0	Channel 4 Single Ended Output
4A	14	ı	Channel 4 Differential Receiver Non-Inverting Input
4B	15	I	Channel 4 Differential Receiver Inverting Input
V <sub>CC</sub>	16	PWR	Device V <sub>CC</sub> (4.75 V to 5.25 V)





NC-No internal connection

Figure 4-2. SN55173: FK Package (Top View)

A. The SN55173 FK package is not recommended for new designs.

Table 4-2. Pin Functions

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.	1176	DESCRIPTION
NC	1, 6, 11, 16		No Connect
1B	2	I	Differential Receiver Inverting Input
1A	3	I	Differential Receiver Non-Inverting Input
1Y	4	0	Single Ended Output
G	5	ı	Active High Enable
2Y	7	0	Single Ended Output
2A	8	I	Differential Receiver Non-Inverting Input
2B	9	I	Differential Receiver Inverting Input
GND	10	GND	Device GND
3B	12	I	Differential Receiver Inverting Input
3A	13	I	Differential Receiver Non-Inverting Input
3Y	14	0	Single Ended Output
G	15	I	Active Low Enable
4Y	17	0	Single Ended Output
4A	18	I	Differential Receiver Non-Inverting Input
4B	19	ı	Receiver Inverting Input
V <sub>CC</sub>	20	PWR	Device VCC

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.



## **5 Specifications**

## **5.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub> (2)	Supply voltage				V
V <sub>I</sub>	Input voltage (A or B inputs)			± 25	V
V <sub>ID</sub> (3)	Differential input voltage			± 25	V
V <sub>I(EN)</sub>	Enable input voltage				V
I <sub>OL</sub>	Low-level output current			50	mA
	Continuous total dissipation		See Dissipation	n Rating Table	
	Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds:	D or N package		260	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds:	J package		300	°C
T <sub>stg</sub>	Storage temperature range		65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 5.2 Dissipation Rating Table

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
FK	1375 mW	11 mW/°C	880 mW	275 mW
J	1375 mW	11 mW/°C	880 mW	275 mW

## **5.3 Recommended Operating Conditions**

		MIN	NOM	MAX	UNIT	
Supply voltage V	SN55173	4.5	5	5.5	V	
Supply voltage, V <sub>CC</sub>	SN75173	4.75	5	5.25	V	
Common-mode input voltage, V <sub>IC</sub>	·			± 12	V	
Differential input voltage, V <sub>ID</sub>				± 12	V	
High-level enable-input voltage, V <sub>IH</sub>	2			V		
Low-level enable-input voltage, V <sub>IL</sub>				8.0	V	
High-level output current, I <sub>OH</sub>			_	- 400	μA	
Low-level output current, I <sub>OL</sub>				16	mA	
Operating free air temperature T	SN55173	- 55	1	25	°C	
Operating free-air temperature, T <sub>A</sub>	SN75173	0	7	'0		

<sup>(2)</sup> All voltage values, except differential input voltage, are with respect to network ground terminal.

<sup>(3)</sup> Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.



#### **5.4 Thermal Information**

	THERMAL METRIC <sup>(1)</sup>	D (SOIC)	N (PDIP)	NS (SOP)	J (CDIP)	UNIT
	THERMAL WETRICKY		UNII			
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	84.6	60.6	88.5	65.6	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	43.5	48.1	46.2	54.6	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	43.2	40.6	50.7	42.1	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	10.4	27.5	13.5	22.9	°C/W
Ψ ЈВ	Junction-to-board characterization parameter	42.8	40.3	50.3	41.6	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

#### 5.5 Electrical Characteristics

over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature

	PARAMETER	TEST CONDITIONS	TEST CONDITIONS			MAX	UNIT
VIT+	Positive-going input threshold voltage	V <sub>O</sub> = 2.7 V,	$I_0 = -0.4 \text{ mA}$			0.2	V
VIT-	Negative-going input threshold voltage	V <sub>O</sub> = 0.5 V,	I <sub>O</sub> = 16 mA		- 0.2 <sup>(2)</sup>		V
Vhys	Hysteresis (V <sub>IT+</sub> – V <sub>IT</sub> )	See Figure 5-1			50		mV
VIK	Enable-input clamp voltage	I <sub>I</sub> = – 18 mA				- 1.5	V
VOH	Lligh level output voltage	\/ = 200 m\/	- 400 ·· A	SN55173	2.5		V
VOH	High-level output voltage	V <sub>ID</sub> = 200 mV,	$I_{OH} = -400 \mu A$	SN75173	2.7		V
VOL	Low lovel output veltage	V 200 V 2 5: 0.4		I <sub>OL</sub> = 8 mA		0.45	V
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV},$	See Figure 6-1	I <sub>OL</sub> = 16 mA		0.5	, v
IOZ	High-impedance-state output current	V <sub>O</sub> = 0.4 V to 2.4 V				± 20	μΑ
	Line input current	Other input at 0.1/	See Note 3	V <sub>I</sub> = 12 V		1	mA
l <sub>l</sub>	Line input current	Other input at 0 V,	See	V <sub>I</sub> = - 7 V		- 0.8	mA
IIH	High-level enable-input current	V <sub>IH</sub> = 2.7 V	1			20	μΑ
IIL	Low-level enable-input current	V <sub>IL</sub> = 0.4 V				- 100	μΑ
rį	Input resistance				12		kΩ
IOS	Short-circuit output current				<b>– 15</b>	- 85	mA
ICC	Supply current	Outputs disabled				70	mA

<sup>(1)</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

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<sup>(2)</sup> The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for threshold voltage levels only.

<sup>(3)</sup> Refer to TIA/EIA-422-B and TIA/EIA-423-B for exact conditions.



# **5.6 Switching Characteristics**

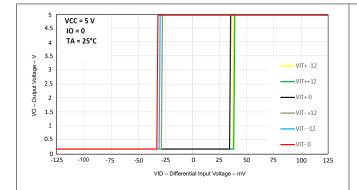
 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	V <sub>ID</sub> = - 1.5 V to 1.5 V,		20	35	ns
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output	C <sub>L</sub> = 15 pF, See Figure 6-1		22	35	ns
t <sub>PZH</sub>	Output enable time to high level	C <sub>L</sub> = 15 pF, See Figure 6-2		17	22	ns
t <sub>PZL</sub>	Output enable time to low level	C <sub>L</sub> = 15 pF, See Figure 6-3		20	25	ns
t <sub>PHZ</sub>	Output disable time from high level	C <sub>L</sub> = 5 pF, See Figure 6-2		21	30	ns
t <sub>PLZ</sub>	Output disable time from low level	C <sub>L</sub> = 5 pF, See Figure 6-3		30	40	ns



### **5.7 Typical Characteristics**

Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



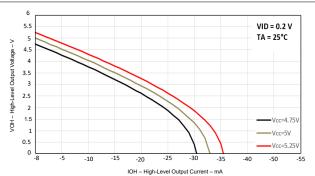
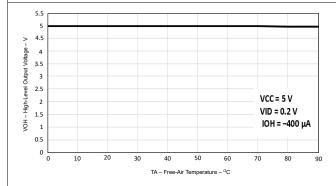


Figure 5-1. Output Voltage vs Differential Input Voltage

Figure 5-2. High-level Output Voltage vs High-level Output Current



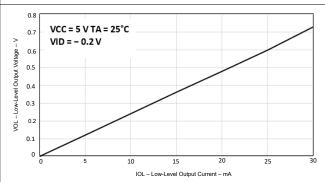
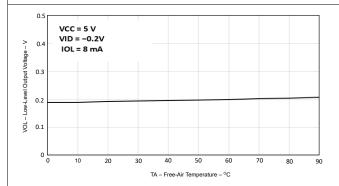


Figure 5-3. High-level Output Voltage vs Free-air Temperature 5

Figure 5-4. Low-level Output Voltage vs Low-level Output Current



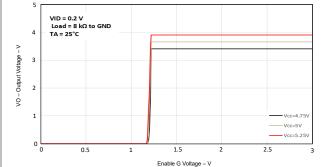
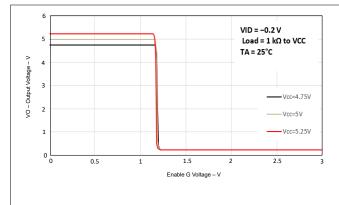


Figure 5-5. Low-level Output Voltage vs Free-air Temperature

Figure 5-6. Output Voltage vs Enable G Voltage





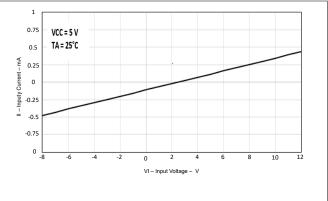
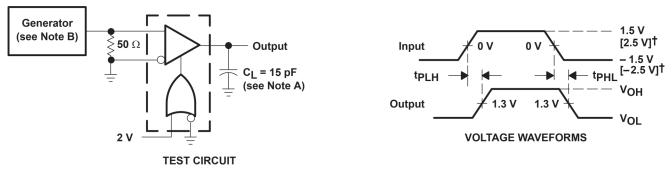


Figure 5-7. Output Voltage vs Enable G Voltage

Figure 5-8. Input Current vs Input Voltage

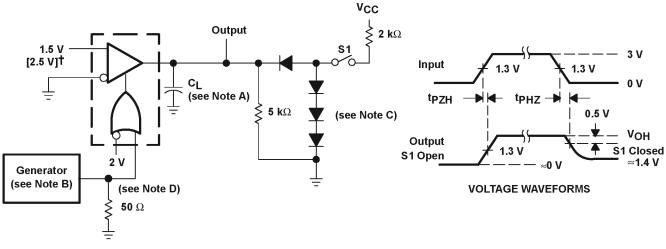


#### **6 Parameter Measurement Information**



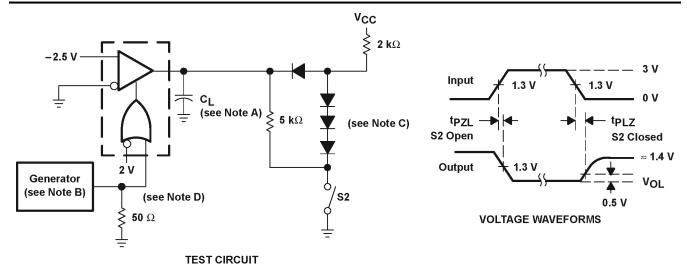
- A. † Voltage for the SN55173 only.
- B. C<sub>L</sub> includes probe and jig capacitance.
- C. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%,  $t_r \le 6$  ns,  $t_f \le 6$  ns,  $t_C \le 6$  ns

Figure 6-1. t<sub>PLH</sub>, T<sub>PHL</sub> Test Circuit and Voltage Waveforms



- **TEST CIRCUIT**
- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%,  $t_r \le 6$  ns,  $t_f \le 6$  ns
- C. All diodes are 1N916, or equivalent.
- D. To test the active-low enable  $\overline{\mathsf{G}},$  ground  $\mathsf{G}$  and apply an inverted input waveform to  $\mathsf{G}.$

Figure 6-2. t<sub>PHZ</sub>, T<sub>PZH</sub> Test Circuit and Voltage Waveforms



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%,  $t_r \le 6$  ns,  $t_f \le 6$  ns,  $t_O = 50$   $\Omega$ .
- C. All diodes are 1N916, or equivalent.
- D. To test the active-low enable G, ground G and apply an inverted input waveform to G.

Figure 6-3. t<sub>PZL</sub>, T<sub>PLZ</sub> Test Circuit and Voltage Waveforms



## 7 Detailed Description

## 7.1 Device Functional Modes

**Table 7-1. Function Table (Each Receiver)** 

DIFFERENTIAL A-B	ENA	BLES <sup>(1)</sup>	OUTPUT Y
DIFFERENTIAL A-B	G	G	OUTFOLL
V <sub>ID</sub> ≥ 0.2 V	Н	Х	Н
VID ≥ 0.2 V	X	L	Н
021/21/2021/	Н	XL	?
-0.2 V < V <sub>ID</sub> < 0.2 V	X		?
V <sub>ID</sub> ≤ -0.2 V	Н	Х	L
V <sub>ID</sub> ≤ -0.2 V	X	L	L
X	L	Н	Z
On an aircuit	Х	L	Н
Open circuit	Н	X	Н

(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

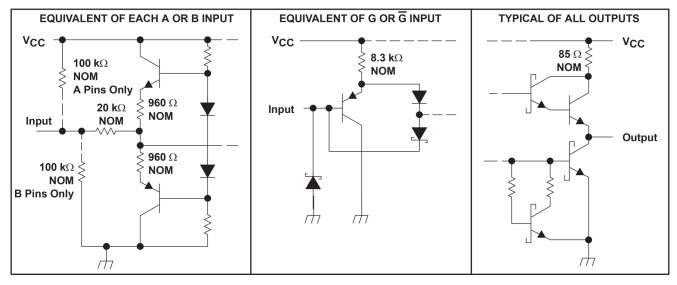


Figure 7-1. Schematics of Inputs and Outputs

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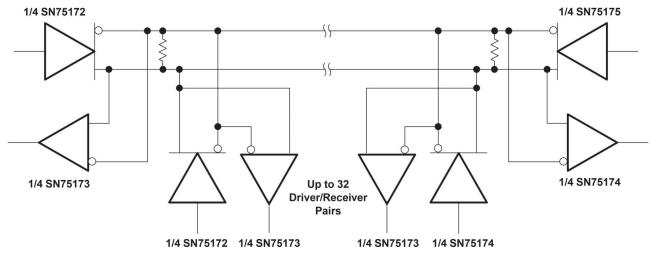


# 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## **8.1 Application Information**



A. The line should be terminated at both ends in its characteristic impedance. Stub lengths off the main line should be kept as short as possible.

Figure 8-1. Typical Application Circuit



## 9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

## 9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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## 9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision E (April 2000) to Revision F (October 2023)

Pag

Changed the numbering format for tables, figures, and cross-references throughout the document......

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN55173J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN55173J
SN55173J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN55173J
SN75173D	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	0 to 70	SN75173
SN75173DR	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75173
SN75173DR.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75173
SN75173N	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75173N
SN75173N.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75173N
SN75173NSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75173
SN75173NSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75173
SNJ55173J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ55173J
SNJ55173J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ55173J

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE OPTION ADDENDUM**

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Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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#### OTHER QUALIFIED VERSIONS OF SN55173, SN75173:

Catalog: SN75173

Military: SN55173

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75173DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75173NSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75173DR	SOIC	D	16	2500	340.5	336.1	32.0
SN75173NSR	SOP	NS	16	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN75173N	N	PDIP	16	25	506	13.97	11230	4.32
SN75173N.A	N	PDIP	16	25	506	13.97	11230	4.32

# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



## NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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